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April 1st, 2010 Renesas Electronics Corporation

Issued by: Renesas Electronics Corporation (http://www.renesas.com)

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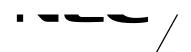
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MOS FIELD EFFECT TRANSISTOR 2SK4080

SWITCHING N-CHANNEL POWER MOS FET

DESCRIPTION

The 2SK4080 is N-channel MOS FET device that features a low on-state resistance and excellent switching characteristics, and designed for low voltage high current applications such as DC/DC converter with synchronous rectifier.

FEATURES

<R>

• Low on-state resistance

 $R_{DS(on)1}$ = 9.0 $m\Omega$ MAX. (Vgs = 10 V, Ip = 24 A)

- Low Qgd: Qgd = 6.3 nC TYP.
- 4.5 V drive available

ORDERING INFORMATION

PART NUMBER	PACKAGE		
2SK4080(1)-S27-AY Note	TO-251 (MP-3-b)		
2SK4080-ZK-E1-AY Note	TO-252 (MP-3ZK)		
2SK4080-ZK-E2-AY Note	TO-252 (MP-3ZK)		

Note Pb-free (This product does not contain Pb in external electrode.)

ABSOLUTE MAXIMUM RATINGS (TA = 25℃)

Drain to Source Voltage (Vgs = 0 V)	VDSS	30	V
Gate to Source Voltage (Vps = 0 V)	Vgss	±20	V
Drain Current (DC) (Tc = 25℃)	I D(DC)	±48	Α
Drain Current (pulse) Note1	D(pulse)	±144	Α
Total Power Dissipation (Tc = 25℃)	P T1	29	W
Total Power Dissipation	P _{T2}	1.0	W
Channel Temperature	Tch	150	${\mathbb C}$
Storage Temperature	Tstg	-55 to +150	${\mathfrak C}$
Single Avalanche Current Note2	las	21	Α
Single Avalanche Energy Note2	Eas	44.1	mJ

Notes 1. PW \leq 10 μ s, Duty Cycle \leq 1%

2. Starting T_{ch} = 25°C, V _{DD} = 15 V, R_G = 25 Ω , V_{GS} = 20 \rightarrow 0 V, L = 100 μ H

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(TO-251)



(TO-252)



ELECTRICAL CHARACTERISTICS (TA = 25°C)

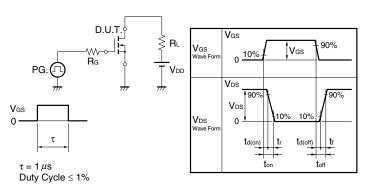
CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Zero Gate Voltage Drain Current	IDSS	V _{DS} = 30 V, V _{GS} = 0 V			10	μΑ
Gate Leakage Current	Igss	Vgs = ±20 V, Vps = 0 V			±100	nA
Gate Cut-off Voltage	V _{GS(off)}	V _{DS} = 10 V, I _D = 1 mA	1.5	2.0	2.5	V
Forward Transfer Admittance Note	yfs	V _{DS} = 10 V, I _D = 12 A	7	14		S
Drain to Source On-state Resistance Note	R _{DS(on)1}	V _{GS} = 10 V, I _D = 24 A		7.0	9.0	mΩ
	R _{DS(on)2}	V _{GS} = 4.5 V, I _D = 24 A		10.2	15	mΩ
Input Capacitance	Ciss	V _{DS} = 10 V		1670		рF
Output Capacitance	Coss	V _G S = 0 V		290		pF
Reverse Transfer Capacitance	Crss	f = 1 MHz		150		pF
Turn-on Delay Time	td(on)	V _{DD} = 15 V		10		ns
Rise Time	tr	ID = 30 A		5.3		ns
Turn-off Delay Time	td(off)	Vgs = 12 V		42		ns
Fall Time	tf	$R_G = 3 \Omega$		6.1		ns
Total Gate Charge	Q _{G1}	V _{DD} = 15 V, V _{GS} = 12 V, I _D = 30 A		32		nC
	Q _{G2}	V _{DD} = 15 V, V _{GS} = 4.5 V, I _D = 30 A		13		nC
Gate to Source Charge	Qgs	VDD = 15 V		4.6		nC
Gate to Drain Charge	Q _{GD}	ID = 30 A		6.3		nC
Gate Resistance	Rg			2.4		Ω
Body Diode Forward Voltage Note	V _F (S-D)	IF = 30 A, VGS = 0 V		0.94	1.5	V
Reverse Recovery Time	trr	IF = 30 A, VGS = 0 V		29		ns
Reverse Recovery Charge	Qrr	di/dt = 100 A/μs		23		nC

Note Pulsed

TEST CIRCUIT 1 AVALANCHE CAPABILITY

$V_{GS} = 20 \rightarrow 0 \text{ V}$ V_{DD} V_{DD} V_{DD} V_{DD} V_{DD} V_{DD} V_{DD} V_{DD} V_{DD} V_{DD}

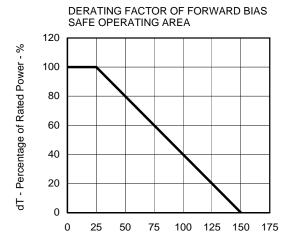
TEST CIRCUIT 2 SWITCHING TIME



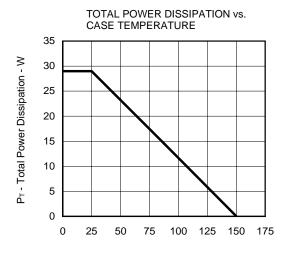
TEST CIRCUIT 3 GATE CHARGE

Starting Tch

TYPICAL CHARACTERISTICS (T_A = 25℃)

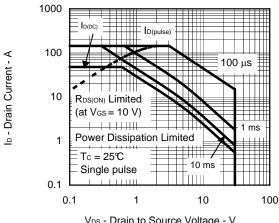


Tc - Case Temperature - °C



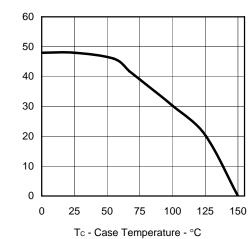
Tc - Case Temperature - °C

FORWARD BIAS SAFE OPERATING AREA



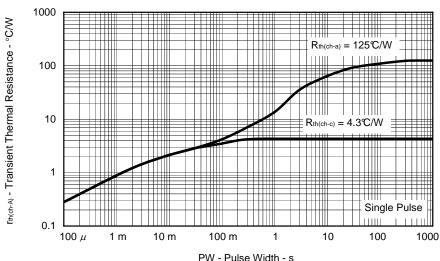
V_{DS} - Drain to Source Voltage - V

DRAIN CURRENT vs. CASE TEMPERATURE



TRANSIENT THERMAL RESISTANCE vs. PULSE WIDTH

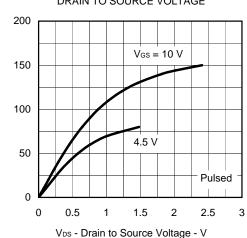
lo - Drain Current - A



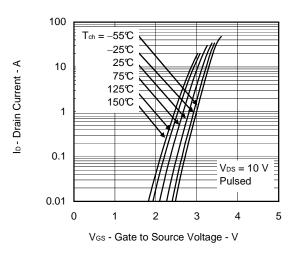
PW - Pulse Width - s

Ip - Drain Current - A

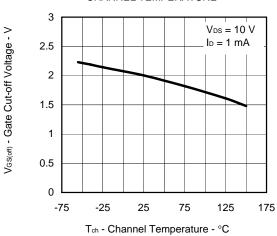
DRAIN CURRENT vs. DRAIN TO SOURCE VOLTAGE



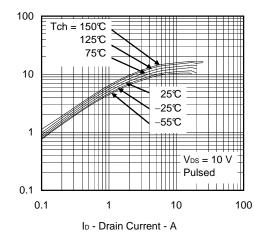
FORWARD TRANSFER CHARACTERISTICS



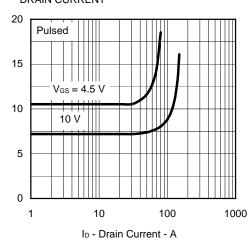
GATE CUT-OFF VOLTAGE vs. CHANNEL TEMPERATURE



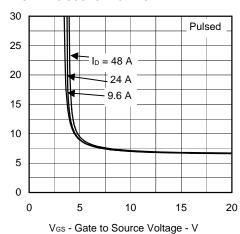
FORWARD TRANSFER ADMITTANCE vs. DRAIN CURRENT



DRAIN TO SOURCE ON-STATE RESISTANCE vs. DRAIN CURRENT



DRAIN TO SOURCE ON-STATERESISTANCE vs. GATE TO SOURCE VOLTAGE

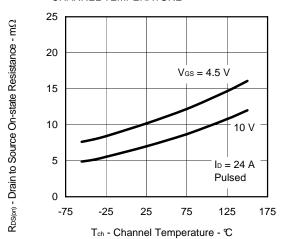


RDS(on) - Drain to Source On-state Resistance - mΩ

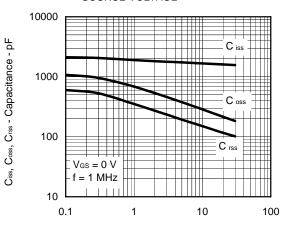
| y_{fs} | - Forward Transfer Admittance - S

RDS(on) - Drain to Source On-state Resistance - m\O

DRAIN TO SOURCE ON-STATE RESISTANCE vs. CHANNEL TEMPERATURE

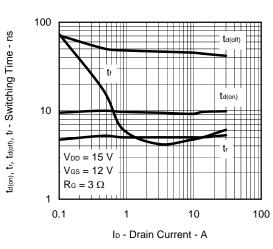


CAPACITANCE vs. DRAIN TO SOURCE VOLTAGE

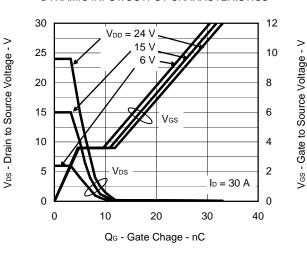


V_{DS} - Drain to Source Voltage - V

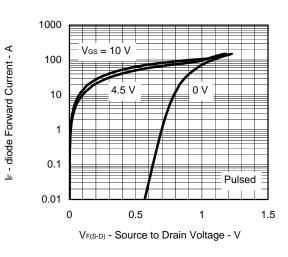
SWITCHING CHARACTERISTICS



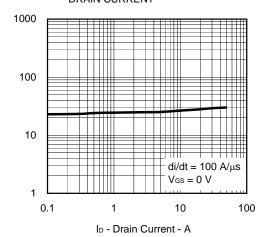
DYNAMIC INPUT/OUTPUT CHARACTERISTICS



SOURCE TO DRAIN DIODE FORWARD VOLTAGE

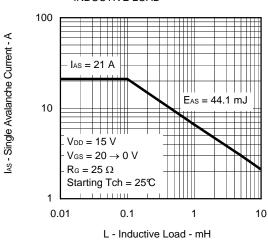


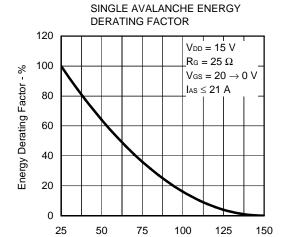
REVWESE RECOVERY TIME vs. DRAIN CURRENT



tr - Reverse Recovery Time - ns

SINGLE AVALANCHE CURRENT vs. INDUCTIVE LOAD

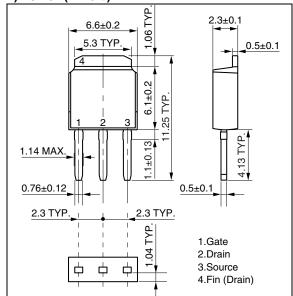


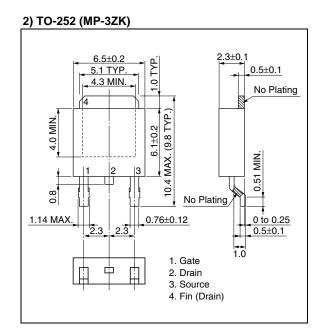


Starting T_{ch} - Starting Channel Temperature - ${\mathfrak C}$

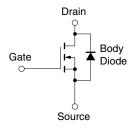
PACKAGE DRAWINGS (Unit: mm)

<R> 1) TO-251 (MP-3-b)





EQUIVALENT CIRCUIT



Remark The diode connected between the gate and source of the transistor serves as a protector against ESD.

When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

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